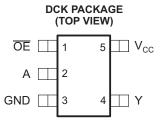
SCES670-MARCH 2007

FEATURES

- Controlled Baseline
 - One Assembly Site
 - One Test Site
 - One Fabrication Site
- Extended Temperature Performance of –55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree (1)
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- I_{off} Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max t_{nd} of 2.5 ns at 1.8 V
- Low Power Consumption, 10-μA Max I_{CC}
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The SN74AUC1G125 is operational at 0.8-V to 2.7-V V_{CC} , but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUC1G125 is a single-line driver with a 3-state output. The output is disabled when the output-enable (OE) input is high.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



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ORDERING INFORMATION(1)

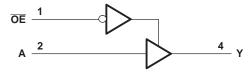
T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING(3)
-55°C to 125°C	SOT (SC-70) - DCK	Reel of 3000	CAUC1G125MDCKREP	UM_

- For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI
 Web site at www.ti.com.
- (2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
- (3) The actual top-side marking has one additional character that designates the assembly/test site.

FUNCTION TABLE

INP	JTS	OUTPUT
ŌĒ	Α	Y
L	Н	Н
L	L	L
Н	X	Z

LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range	-0.5	3.6	V	
VI	Input voltage range (2)		-0.5	3.6	V
Vo	Voltage range applied to any output in t	the high-impedance or power-off state (2)	-0.5	3.6	V
Vo	Output voltage range ⁽²⁾	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0 V		-50	mA
I _{OK}	Output clamp current	V _O < 0 V		-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V _{CC} or GNI	D		±100	mA
θ_{JA}	Package thermal impedance (3)		252	°C/W	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT	
V_{CC}	Supply voltage		0.8	2.7	V	
		V _{CC} = 0.8 V	V _{CC}			
V_{IH}	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$		V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7			

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.





Recommended Operating Conditions (continued)

			MIN	MAX	UNIT
		V _{CC} = 0.8 V		0	
V_{IL}	Low-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 0.8 V		-0.7	
		V _{CC} = 1.1 V		-3	
I _{OH}	High-level output current	V _{CC} = 1.4 V		-5	mA
		V _{CC} = 1.65 V		-8	
		V _{CC} = 2.3 V		-9	
		V _{CC} = 0.8 V		0.7	
		V _{CC} = 1.1 V		3	
I_{OL}	Low-level output current	V _{CC} = 1.4 V		5	mA
		V _{CC} = 1.65 V		8	
		V _{CC} = 2.3 V		9	
		V _{CC} = 0.8 V to 1.6 V		20	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 1.65 V to 1.95 V		10	ns/V
		V _{CC} = 2.3 V to 2.7 V		3	
T _A	Operating free-air temperature		-55	125	°C

SN74AUC1G125-EP SINGLE BUS BUFFER GATE WITH 3-STATE OUTPUT

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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP(1)	MAX	UNIT
	$I_{OH} = -100 \mu\text{A}$	0.8 V to 2.7 V	V _{CC} – 0.1		
	$I_{OH} = -0.7 \text{ mA}$	0.8 V	0.55		
V	$I_{OH} = -3 \text{ mA}$	1.1 V	0.8		V
V _{OH}	$I_{OH} = -5 \text{ mA}$	1.4 V	1		V
	$I_{OH} = -8 \text{ mA}$	1.65 V	1.2		
	$I_{OH} = -9 \text{ mA}$	2.3 V	1.8		
	$I_{OL} = 100 \mu\text{A}$	0.8 V to 2.7 V		0.2	
	I _{OL} = 0.7 mA	0.8 V	0.25	0.3	V
V	I _{OL} = 3 mA	1.1 V			
V _{OL}	$I_{OL} = 5 \text{ mA}$	1.4 V		0.4	V
	$I_{OL} = 8 \text{ mA}$	1.65 V		0.45	
	I _{OL} = 9 mA	2.3 V		0.6	
I _I A or $\overline{\text{OE}}$ input	$V_I = V_{CC}$ or GND	0 V to 2.7 V		±5	μΑ
l _{off}	V_I or $V_O = 2.7 \text{ V}$	0 V		±10	μΑ
I _{OZ}	$V_O = V_{CC}$ or GND	2.7 V		±10	μΑ
I _{cc}	$V_I = V_{CC}$ or GND, $I_O = 0$	0.8 V to 2.7 V		10	μΑ
C _I	$V_I = V_{CC}$ or GND	2.5 V			pF
C _o	$V_O = V_{CC}$ or GND	2.5 V	5.5		pF

⁽¹⁾ All typical values are at $T_A = 25^{\circ}C$.

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 0.8 V	V _{CC} = ± 0.		V _{CC} = ± 0.			_C = 1.8 : 0.15 \		V _{CC} = ± 0.		UNIT
	(INPOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX	
t _{pd}	Α	Υ	4.7	0.8	7.5	0.4	6	0.7	5	5.5	0.9	5	ns
t _{en}	ŌĒ	Υ	5.4	0.7	7.8	0.5	7	1	5.5	6.5	1.1	5	ns
t _{dis}	ŌĒ	Y	4.8	1.4	8.3	1.4	7	1.8	6	6.8	0.8	6	ns

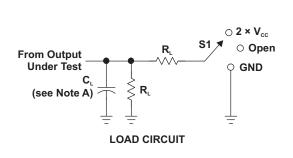
Operating Characteristics

 $T_A = 25^{\circ}C$

PARAMETER		TEST	$V_{CC} = 0.8 V$	V _{CC} = 1.2 V	V _{CC} = 1.5 V	V _{CC} = 1.8 V	V _{CC} = 2.5 V	UNIT	
	FARAMETER		CONDITIONS	TYP	TYP	TYP	TYP	TYP	ONIT
C _{pd}	Power dissipation	Outputs enabled	f = 10 MHz	14	14	14	15	16	pF
	capacitance	Outputs disabled	1 = 10 WIDZ	1.5	1.5	1.5	2	2.5	pΕ

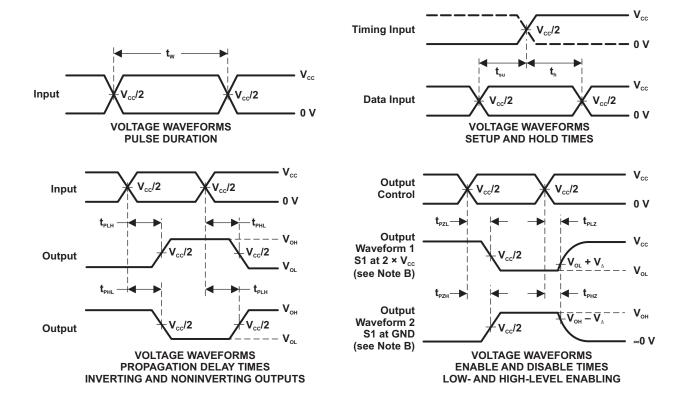


PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t_{PLZ}/t_{PZL}	2 × V _{cc}
t _{PHZ} /t _{PZH}	GND

V _{cc}	C _L	R _L	V _Δ
0.8 V	15 pF	2 k Ω	0.1 V
1.2 V ± 0.1 V	15 pF	2 k Ω	0.1 V
1.5 V ± 0.1 V	15 pF	2 k Ω	0.1 V
1.8 V ± 0.15 V	15 pF	2 k Ω	0.15 V
$2.5~V~\pm~0.2~V$	15 pF	2 k Ω	0.15 V
1.8 V ± 0.15 V	30 pF	1 k Ω	0.15 V
2.5 V ± 0.2 V	30 pF	500 Ω	0.15 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_o = 50 Ω , slew rate \geq 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. $t_{\text{\tiny PLZ}}$ and $t_{\text{\tiny PHZ}}$ are the same as $t_{\text{\tiny dis}}$.
- F. $t_{\mbox{\tiny PZL}}$ and $t_{\mbox{\tiny PZH}}$ are the same as $t_{\mbox{\tiny en}}.$
- G. t_{PlH} and t_{PHl} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
CAUC1G125MDCKREP	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CAY
V62/06656-01XE	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CAY

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74AUC1G125-EP:

Catalog: SN74AUC1G125

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

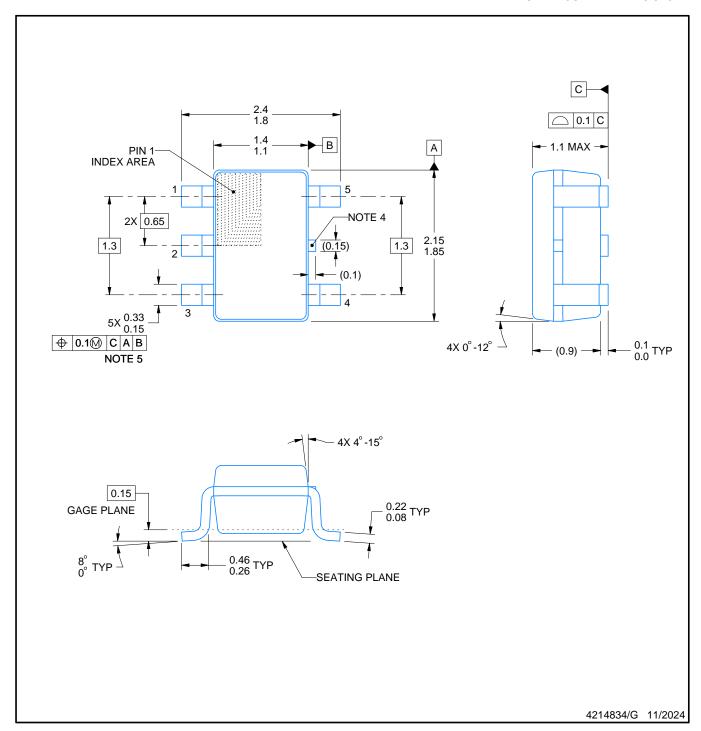
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NOTE: Qualified Version Definitions:

 $_{\bullet}$ Catalog - TI's standard catalog product



SMALL OUTLINE TRANSISTOR



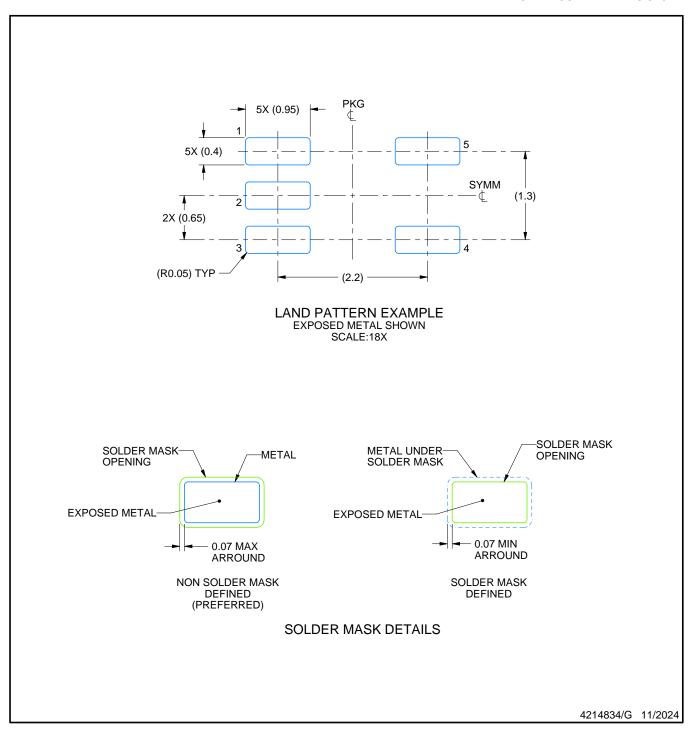
NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



SMALL OUTLINE TRANSISTOR

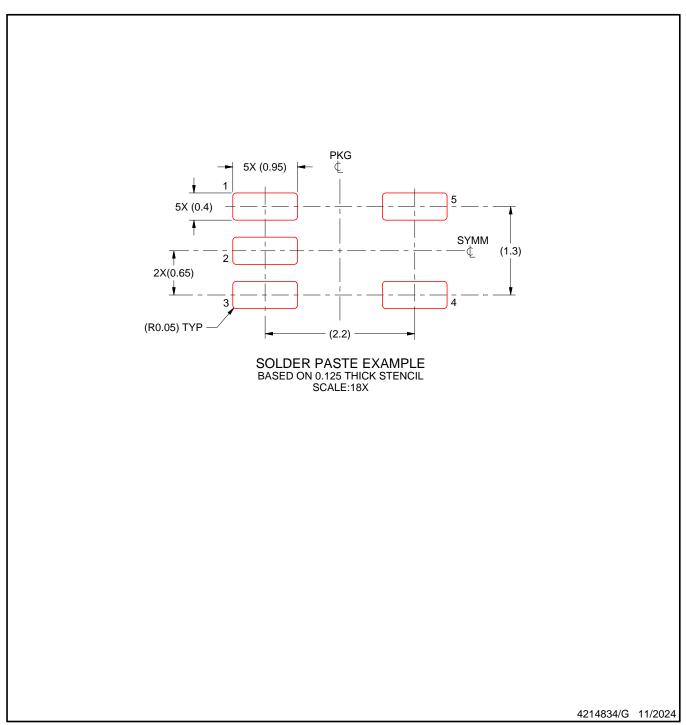


NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.



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